rfmd.com

RF3861

WIDE BANDWIDTH, HIGH LINEARITY LOW NOISE AMPLIFIER

Package Style: QFN, 16-Pin, 3mmx3mm

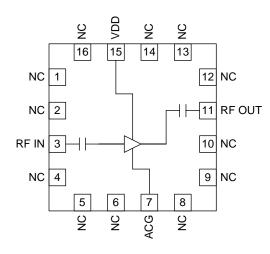


Features

- Low Noise and High Intercept Point
- Adjustable Bias for Enhanced IP3
- Single 2.5V to 6.0V Power Supply
- 400 MHz to 3800 MHz Operation
- QFN16, 3mmx3mm Package

Applications

- GSM/EDGE, CDMA, PCS, UMTS LNA/Linear Driver
- WLAN LNA/Linear Driver
- WiMAX LNA/Linear Driver
- 900MHz LNA/Linear Driver
- General Purpose Amplification



Functional Block Diagram

Product Description

The RF3861 is a low noise amplifier with a high output IP3. The amplifier is self-biased from a single voltage supply with 50Ω input and output ports. The useful frequency range is from 400MHz to 3800MHz. A 1dB noise figure and 36dBm OIP3 performance is achieved with a 5V $V_{DD},\,90\,\text{mA}.$ Current can be increased to raise OIP3 while having minimal effect on noise figure. The IC is featured in a standard QFN, 16-pin, $3\,\text{mmx}3\,\text{mm}$ package.

Ordering Information

RF3861 Wide Bandwidth, High Linearity Low Noise Amplifier
RF3861PCK-410 Fully Assembled Evaluation Board with 5 Sample Parts

 $1.5\,\mbox{GHz}$ to $2.7\,\mbox{GHz}$

RF3861PCK-411 3.3 GHz to 3.8 GHz RF3861PCK-412 700 MHz to 1100 MHz

Optimum Technology Matching® Applied

| ☐ GaAs HBT | ☐ SiGe BiCMOS | ▼ GaAs pHEMT | ☐ GaN HEMT |
|---------------|---------------|--------------|------------|
| ☐ GaAs MESFET | ☐ Si BiCMOS | ☐ Si CMOS | |
| ☐ InGaP HBT | ☐ SiGe HBT | ☐ Si BJT | |

RF3861



Absolute Maximum Ratings

| Parameter | Rating | Unit |
|--------------------------------|-------------|----------|
| Supply Voltage | 6V | V_{DC} |
| Input RF Level | +10 | dBm |
| Current Drain, I _{DD} | 150 | mA |
| Operating Ambient Temperature | -40 to +85 | °C |
| Storage Temperature | -40 to +150 | °C |

Note 1: Max continuous RF IN is $\pm 10\,\mathrm{dBm}$. The max transient RF IN is $\pm 20\,\mathrm{dBm}$.



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

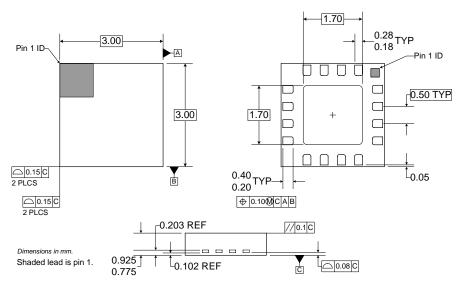
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| Parameter | Specification | | Unit | Condition | |
|--------------------------|---------------|------|------|-----------|--|
| raidilletei | Min. | Тур. | Max. | UIIIL | Condition |
| High Band | | | | | |
| Frequency | 3.3 | 3.5 | 3.8 | GHz | V _{DD} =5V |
| Current | | 90 | 110 | mA | |
| Gain | | 10 | | dB | At 3.5 GHz |
| Noise Figure | | 1.1 | | dB | +25°C, V _{DD} =5V, I _{DD} =90mA, 3500MHz unless specified |
| OIP3 | | 37.0 | | dBm | |
| OP1dB | | 22.0 | | dBm | |
| S11 | | -12 | | dB | f ₁ =3500MHz, f ₂ =3501MHz |
| S22 | | -18 | | dB | |
| Mid Band | | | | | |
| Frequency | 1500 | | 2700 | MHz | |
| Current | | 90 | 110 | mA | V _{DD} =5V |
| Gain | 13.5 | 14.5 | 16.5 | dB | +25°C, V _{DD} =5V, I _{DD} =90 mA, 2000 MHz unless specified |
| Noise Figure | | 1.0 | 1.2 | dB | |
| OIP3 | 33.0 | 35.5 | | dBm | f ₁ =2000MHz, f ₂ =2001MHz |
| OP1dB | 21.0 | 22.5 | 25.0 | dBm | |
| S11 | | -10 | | dB | |
| S22 | | -20 | | dB | |
| Low Band | | | | | |
| Frequency | 700 | | 1100 | MHz | |
| Current | | 90 | 110 | mA | V _{DD} =5V |
| Gain | | 16 | | dB | +25°C, V _{DD} =5V, I _{DD} =90mA, 850MHz unless specified |
| Noise Figure | | 1.2 | | dB | |
| OIP3 | | 36.0 | | dBm | f ₁ =850MHz, f ₂ =851MHz |
| OP1dB | | 22.5 | | dBm | |
| S11 | | -14 | | dB | |
| S22 | | -18 | | dB | |
| Thermal | | | | | |
| Theta _{JC} | | 51 | | °C/W | |
| Power Supply | | | | | |
| Device Operating Voltage | 2.5 | 5.0 | 6.0 | V | |
| Operating Current | 65 | 90 | 110 | mA | V _{DD} =5.0V, R2=open |



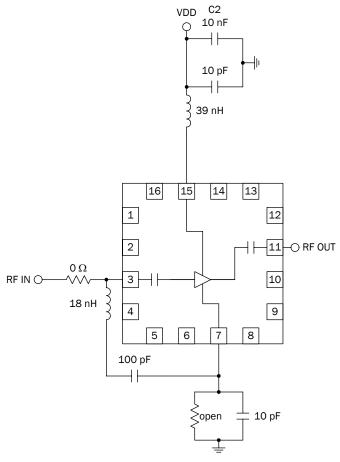
| Pin | Function | Description | Interface Schematic |
|-------------|----------|---|---------------------|
| 1 | NC | Not connected. | |
| 2 | NC | Not connected. | |
| 3 | RF IN | RF input pin. 50Ω matched. This pin is DC-blocked. | |
| 4 | NC | Not connected. | |
| 5 | NC | Not connected. | |
| 6 | NC | Not connected. | |
| 7 | ACG | AC ground. Shunt cap may be added for tuning. Shunt resistor may be added to increase I _{DD} /IP3. | |
| 8 | NC | Not connected. | |
| 9 | NC | Not connected. | |
| 10 | NC | Not connected. | |
| 11 | RF OUT | RF output pin. 50Ω matched. This pin is DC-blocked. | |
| 12 | NC | Not connected. | |
| 13 | NC | Not connected. | |
| 14 | NC | Not connected. | |
| 15 | VD | Bias voltage. 2.5V to 6.0V applied through bias inductor. | |
| 16 | NC | Not connected. | |
| Pkg Base | GND | Ground connection. | |

Package Drawing





Application Schematic 400 MHz to 1300 MHz

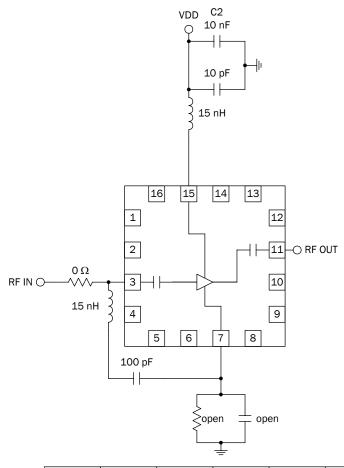


| FREQ | VCC | NF | GAIN | OIP3 | OP1dB |
|------|-------|-----|-------|-------|-------|
| MHz | Volts | dB | dB | dBm | dBm |
| 400 | 5 | 1.7 | 15.23 | 35.45 | 21.27 |
| 600 | 5 | 1.4 | 15.81 | 37.33 | 21.84 |
| 800 | 5 | 1.2 | 16.49 | 36.56 | 22.05 |
| 1000 | 5 | 1.1 | 16.7 | 36.22 | 22.02 |
| 1300 | 5 | 1.1 | 15.28 | 36.88 | 22.19 |

Note: This schematic is equivalent to standard 700 MHz to 1100 MHz evaluation board. Specification in above table shows tested performance over extended frequency range. See Theory of Operation section for details.



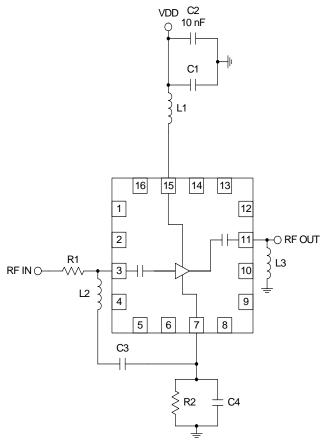
Application Schematic 800 MHz to 2200 MHz



| FREQ | VCC | NF | GAIN | OIP3 | OP1dB |
|------|-------|-----|------|------|-------|
| MHz | Volts | dB | dB | dBm | dBm |
| 800 | 5 | 1.3 | 16 | 36 | 22 |
| 2200 | 5 | 0.9 | 13.9 | 36 | 22 |



Evaluation Board Schematic 700 MHz to 3800 MHz

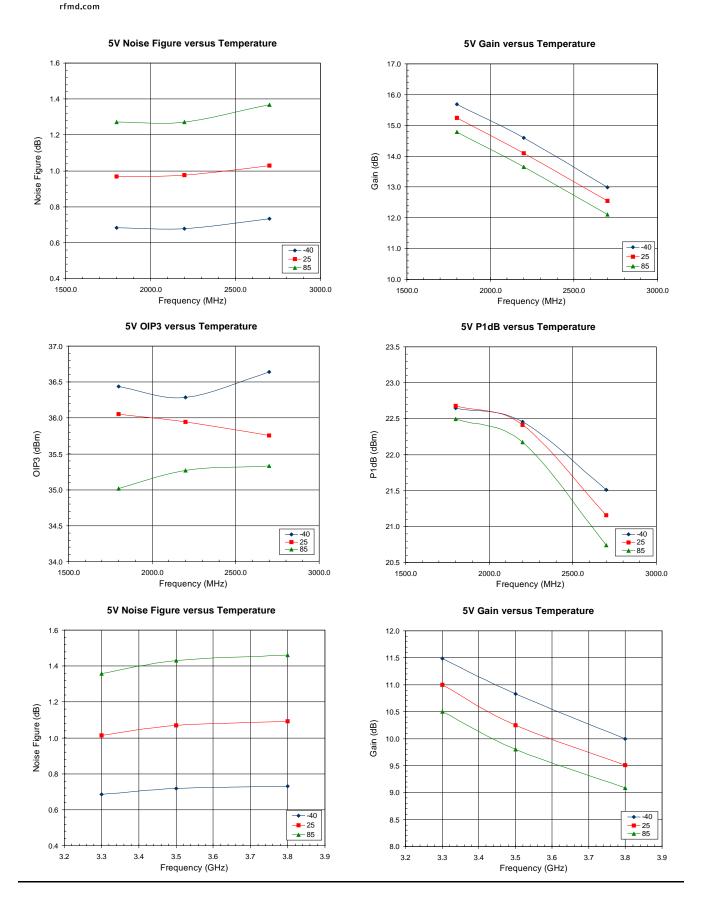


| Components | 700-1100 MHz | 1.5-2.7 GHz | 3.3-3.8 GHz |
|------------|--------------|-------------|-------------|
| C1 (pF) | 10 | 10 | 10 |
| C3 (pF) | 100 | 100 | 100 |
| C4 (pF) | 10 | DNP | DNP |
| L1 (nH) | 39 | 3.9 | 2.2 |
| L2 (nH) | 18 | 4.7 | 4.7 |
| R1 (ohm) | 0 | 0 | 0 |
| R2 (ohm) | DNP | DNP | DNP |
| L3 (nH) | DNP | DNP | DNP |

R2 is DNP for standard 90 mA current draw. If R2 is added, the I_{DD} will increase. A 20 Ω R2 will raise the current to achieve higher linearity.



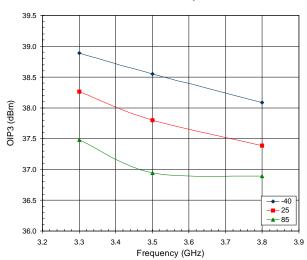




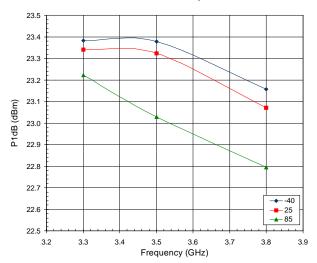
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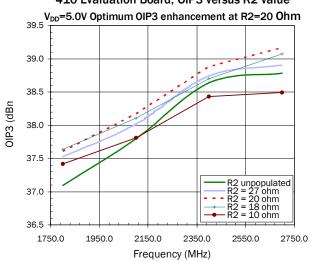




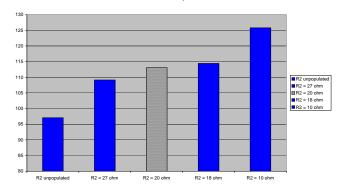
5V P1dB versus Temperature



410 Evaluation Board, OIP3 versus R2 value



RF3861 lcc vs R2 Vdd = 5.0 VR2 = 20 ohm for optimal OIP3





Theory of Operation

Low noise figure/high IP3 make RF3861 ideal for use as both receive LNA and transmit driver for cellular/DCS/PCS/UMTS and WiMax platforms, in addition to many other general purpose applications. Standard evaluation boards cover 700MHz to 1100MHz, 1500MHz to 2700MHz, and 3300MHz to 3800MHz. Viewing the data sheet evaluation board schematic, refer to below for purpose/function of external components:

- R1/L3 (0Ω/unpopulated on standard evaluation boards): These unused components were placed for convenience and flexibility when needed to optimize matching for an out of band application.
- · L2/C3/C4: Placed to optimize input match, and enhance out of band low frequency stability.
- R2: Optionally placed to increase bias current and IP3. It has been found that 20Ω value is best case (see graph section of data sheet).
- L1/C1: Influence output return loss.

RF3861 has internal DC blocking capacitors at RFin/RFout. In addition, it has been shown impedance seen looking out at pins 7/15 influence response. As a result, two port s-parameters become non-applicable. In the event matching is desired for frequency bands outside of those provided with standard evaluation boards, the following approach can be used:

- Start with matching seen for standard evaluation board closest to desired band of operation.
- Optimize values at L2/C4/L1 to obtain response/performance.

The application schematic section of data sheet shows matching arrived at using above procedure, for 400MHz to 1300MHz and 800MHz to 2200MHz. These schematics, along with standard evaluation boards, cover 82% of the useable bandwidth from 400MHz to 3800MHz.

One interesting note concerning these application schematics, the 400MHz to 1300MHz example shows same component values as seen with 700MHz to 1100MHz evaluation board. So, it is, in actuality, the same board. The specification chart next to the schematic simply extends the frequency band by 500MHz. Input and output return losses are better than 10dB over the entire 900MHz bandwidth.

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